



## Dual P-Channel 1.8 V (G-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
- 8	0.090 at $V_{GS} = -4.5 \text{ V}$	± 4.1		
	0.130 at V <sub>GS</sub> = - 2.5 V	± 3.4		
	0.180 at V <sub>GS</sub> = - 1.8 V	± 2.9		

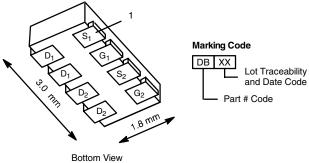
#### **FEATURES**

- Halogen-free According to IEC 61249-2-21
- TrenchFET® Power MOSFETs: 1.8 V Rated
- Compliant to RoHS Directive 2002/95/EC



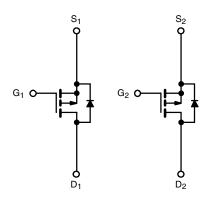


## 1206-8 ChipFET®



Ordering Information: Si5905DC-T1-E3 (Lead (Pb)-free)

Si5905DC-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted							
Parameter		Symbol	5 s	Steady State	Unit		
Drain-Source Voltage		V <sub>DS</sub>	- 8		V		
Gate-Source Voltage		V <sub>GS</sub>	± 8		v		
Continuous Drain Current (T <sub>.I</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	± 4.1	± 3.0	А		
Continuous Diain Current (1, = 150 °C)	T <sub>A</sub> = 85 °C		± 2.9	± 2.2			
Pulsed Drain Current		I <sub>DM</sub>	± 10		A		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	- 1.8	- 0.9			
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	2.1	1.1	W		
Maximum Fower Dissipation	T <sub>A</sub> = 85 °C		1.1	0.6	VV		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C		
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>			260				

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	t ≤ 5 s	R <sub>thJA</sub>	50	60	
Maximum sunction-to-Ambient	Steady State		90	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State		30	40	

- a. Surface mounted on 1" x 1" FR4 board.
- b. See reliability manual for profile. The ChipFET is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

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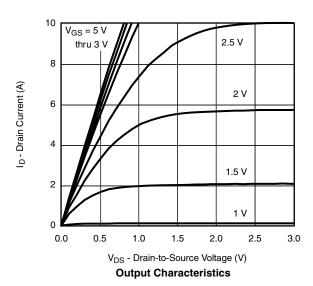
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.45			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 6.4 V, V <sub>GS</sub> = 0 V	6.4 V, V <sub>GS</sub> = 0 V		- 1		
		$V_{DS} = -6.4 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			- 5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 10			Α	
Drain-Source On-State Resistance <sup>a</sup>	, ,	$V_{GS} = -4.5 \text{ V}, I_D = -3 \text{ A}$		0.075	0.090	Ω	
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = - 2.5 A		0.110	0.130		
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 1.0 A		0.150	0.180		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 5 V, I <sub>D</sub> = - 3 A		7		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 0.9 A, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V	
Dynamic <sup>b</sup>			•	•			
Total Gate Charge	$Q_g$			5.5	9		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -4 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -3 \text{ A}$		0.5		nC	
Gate-Drain Charge	$Q_{gd}$			1.5			
Turn-On Delay Time	t <sub>d(on)</sub>			10	15		
Rise Time	t <sub>r</sub>	$V_{DD} = -4 \text{ V}, R_{L} = 4 \Omega$		45	70	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ - 1 A, $V_{GEN} =$ - 4.5 V, $R_g = 6 \Omega$		30	45		
Fall Time	t <sub>f</sub>			10	15		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 0.9 A, dI/dt = 100 A/μs		30	60		

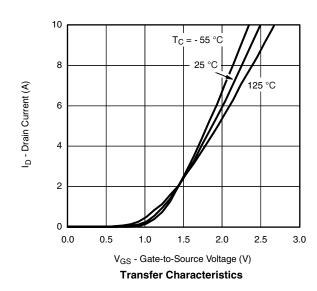
#### Notes

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



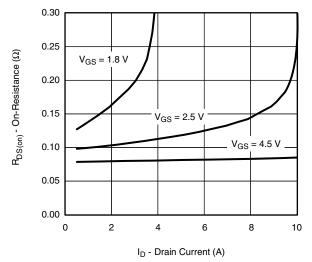




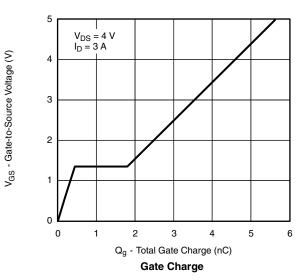




#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



#### **On-Resistance vs. Drain Current**



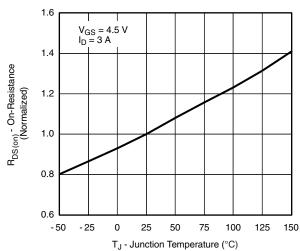
 $T_{J} = 150 \, ^{\circ}\text{C}$   $T_{J} = 25 \, ^{\circ}\text{C}$ 1 0.0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 V<sub>SD</sub> - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

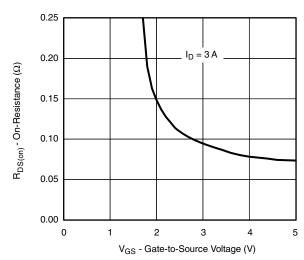
1000 800 C<sub>iss</sub> 600 C<sub>rss</sub> C<sub>oss</sub> 0 0 200 0 2 4 6 8

V<sub>DS</sub> - Drain-to-Source Voltage (V)

#### Capacitance



On-Resistance vs. Junction Temperature



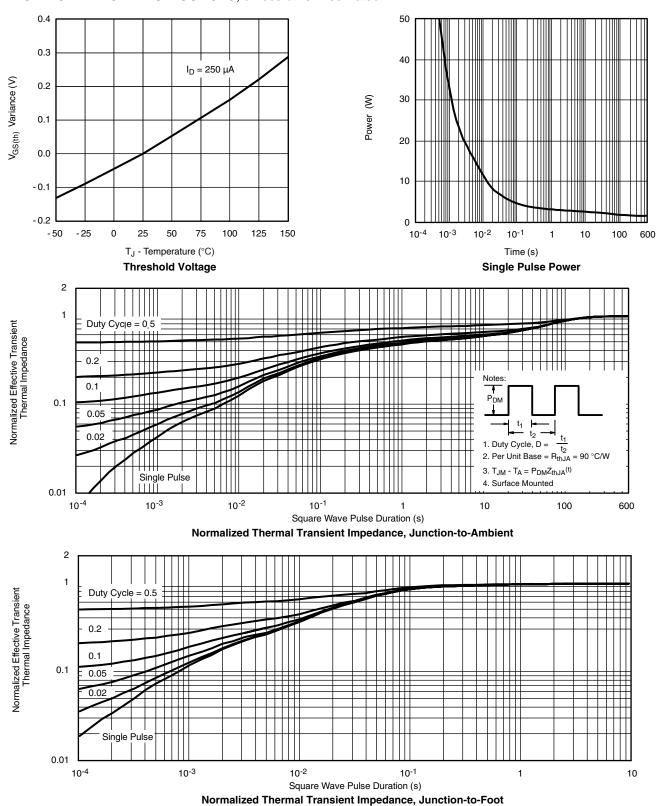
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Is - Source Current (A)

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#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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